

54F/74F258A

Quad 2-Input Multiplexer with TRI-STATE® Outputs

General Description

The 'F258A is a quad 2-input multiplexer with TRI-STATE outputs. Four bits of data from two sources can be selected using a common data select input. The four outputs present the selected data in the complement (inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable ($\overline{OE}$) input, allowing the outputs to interface directly with bus-oriented systems.

Features

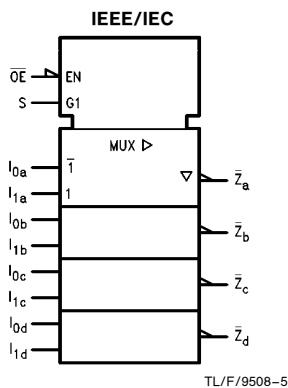
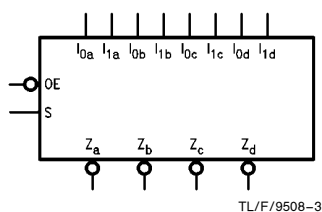
- Multiplexer expansion by tying outputs together
- Inverting TRI-STATE outputs
- Guaranteed 4000V minimum ESD protection

Commercial	Military	Package Number	Package Description
74F258APC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line
	54F258ADM (Note 2)	J16A	16-Lead Ceramic Dual-In-Line
74F258ASC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC
74F258ASJ (Note 1)		M16D	16-Lead (0.300" Wide) Molded Small Outline, EIAJ
	54F258AFM (Note 2)	W16A	16-Lead Cerpack
	54F258ALL (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

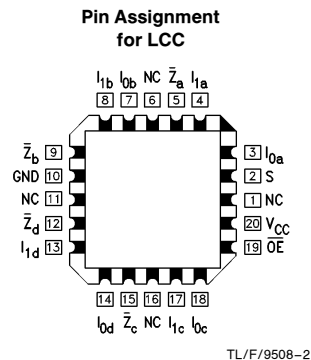
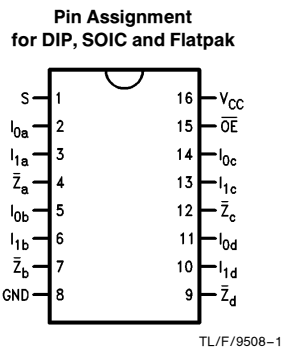
Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbols



Connection Diagrams



TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Unit Loading/Fan Out

Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}
S	Common Data Select Input	1.0/1.0	20 μA/ −0.6 mA
$\overline{OE}$	TRI-STATE Output Enable Input (Active LOW)	1.0/1.0	20 μA/ −0.6 mA
I _{0a} –I _{0d}	Data Inputs from Source 0	1.0/1.0	20 μA/ −0.6 mA
I _{1a} –I _{1d}	Data Inputs from Source 1	1.0/1.0	20 μA/ −0.6 mA
$\overline{Z_a}$ – $\overline{Z_d}$	TRI-STATE Inverting Data Outputs	150/40 (33.3)	−3 mA/24 mA (20 mA)

Functional Description

The 'F258A is a quad 2-input multiplexer with TRI-STATE outputs. It selects four bits of data from two sources under control of a common Select input (S). When the Select input is LOW, the I_{0x} inputs are selected and when Select is HIGH, the I_{1x} inputs are selected. The data on the selected inputs appears at the outputs in inverted form. The 'F258A is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equation for the outputs is shown below:

$$\overline{Z_n} = \overline{OE} \bullet (I_{1n} \bullet S + I_{0n} \bullet \overline{S})$$

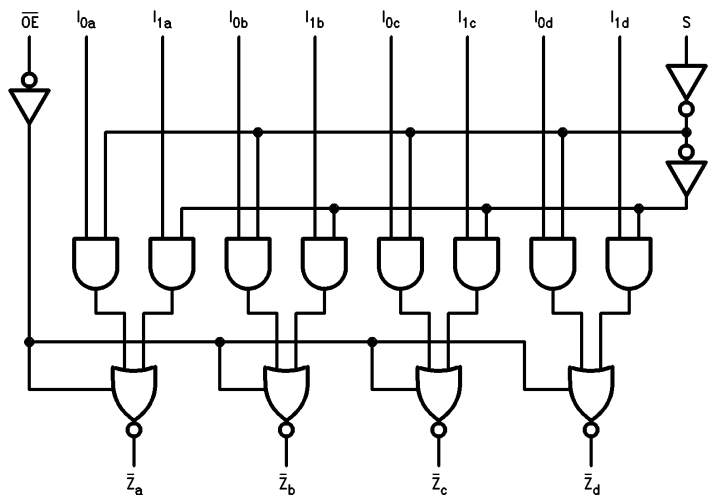
When the Output Enable input ($\overline{OE}$) is HIGH, the outputs are forced to a high impedance OFF state. If the outputs of the TRI-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to TRI-STATE devices whose outputs are tied together are designed so there is no overlap.

Truth Table

Output Enable	Select Input	Data Inputs		Output
$\overline{OE}$	S	I ₀	I ₁	$\overline{Z}$
H	X	X	X	Z
L	H	X	L	H
L	H	X	H	L
L	L	L	X	H
L	L	H	X	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



TL/F/9508-4

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V _{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V _{CC} = 0V)	
Standard Output	−0.5V to V _{CC}
TRI-STATE Output	−0.5V to +5.5V

Current Applied to Output in LOW State (Max) twice the rated I_{OL} (mA)

ESD Last Passing Voltage (Min) 4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

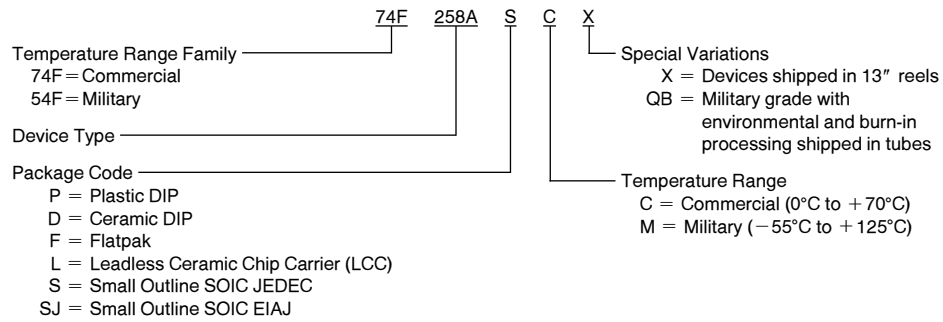
Symbol	Parameter		54F/74F			Units	V _{CC}	Conditions
			Min	Typ	Max			
V _{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I _{IN} = −18 mA
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 54F 10% V _{CC} 74F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC} 74F 5% V _{CC}	2.5 2.4 2.5 2.4 2.7 2.7			V	Min	I _{OH} = −1 mA I _{OH} = −3 mA I _{OH} = −1 mA I _{OH} = −3 mA I _{OH} = −1 mA I _{OH} = −3 mA
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	V	Min	I _{OL} = 20 mA I _{OL} = 24 mA
I _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μA	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μA	Max	V _{IN} = 7.0V
I _{CEX}	Output HIGH Leakage Current	54F 74F			250 50	μA	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test	74F	4.75			V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OD}	Output Leakage Circuit Current	74F			3.75	μA	0.0	V _{IOD} = 150 mV All Other Pins Grounded
I _{IL}	Input LOW Current				−0.6	mA	Max	V _{IN} = 0.5V
I _{OZH}	Output Leakage Current				50	μA	Max	V _{OUT} = 2.7V
I _{OZL}	Output Leakage Current				−50	μA	Max	V _{OUT} = 0.5V
I _{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V _{OUT} = 0V
I _{ZZ}	Bus Drainage Test				500	μA	0.0V	V _{OUT} = V _{CC}
I _{CCH}	Power Supply Current			6.2	9.5	mA	Max	V _O = HIGH
I _{CCL}	Power Supply Current			15.1	23	mA	Max	V _O = LOW
I _{CCZ}	Power Supply Current			11.3	17	mA	Max	V _O = HIGH Z

AC Electrical Characteristics

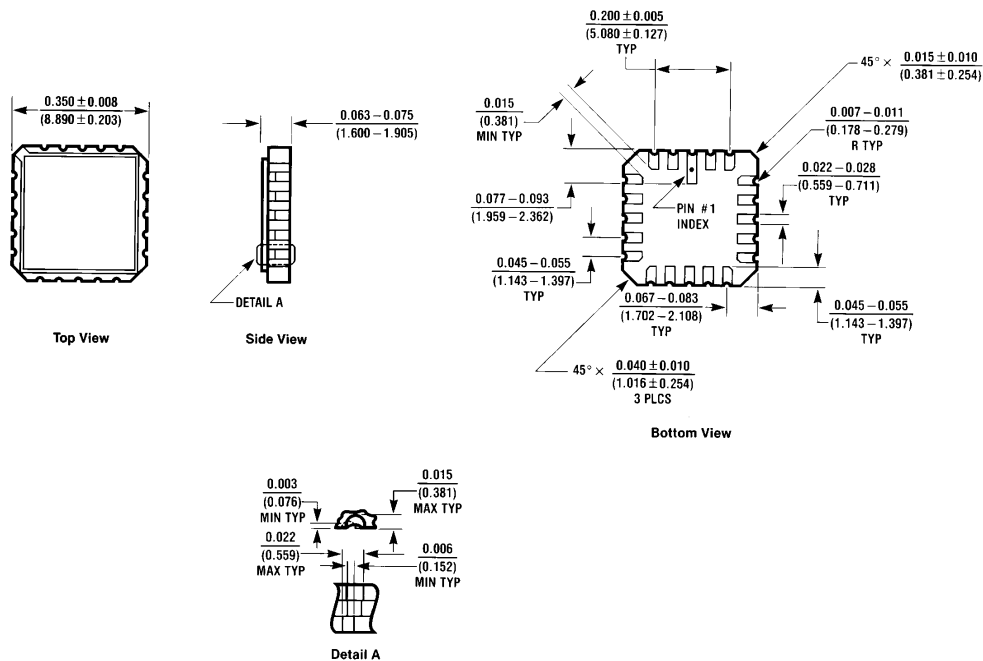
Symbol	Parameter	74F			54F		74F		Units
		$T_A = +25^{\circ}\text{C}$ $V_{CC} = +5.0\text{V}$ $C_L = 50\text{ pF}$			$T_A, V_{CC} = \text{Mil}$ $C_L = 50\text{ pF}$		$T_A, V_{CC} = \text{Com}$ $C_L = 50\text{ pF}$		
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay I_n to $\bar{Z}_n$	2.5 1.0		5.3 4.0	2.0 1.0	7.5 6.0	2.0 1.0	6.0 5.0	ns
t_{PLH} t_{PHL}	Propagation Delay S to $\bar{Z}_n$	3.0 2.5		7.5 7.0	3.0 2.5	9.5 9.0	3.0 2.5	8.5 8.0	ns
t_{PZH} t_{PZL}	Output Enable Time	2.0 2.5		6.0 7.0	2.0 2.5	8.0 9.0	2.0 2.5	7.0 8.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time	2.0 2.0		6.0 6.0	1.5 2.0	7.0 8.5	2.0 2.0	7.0 7.0	

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)



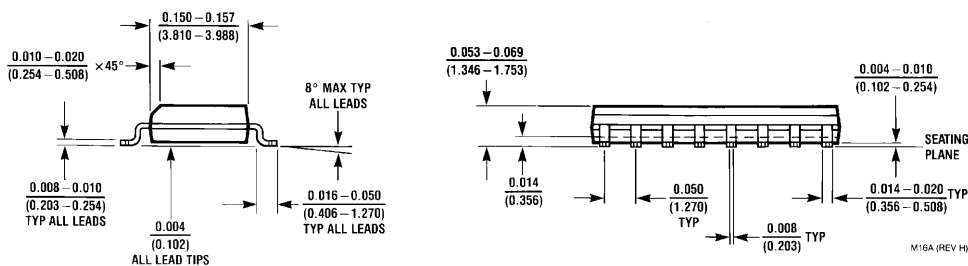
20-Lead Ceramic Leadless Chip Carrier (L)
NS Package Number E20A

E20A (REV D)

The image contains three mechanical drawings of the J16A (REV L) package:

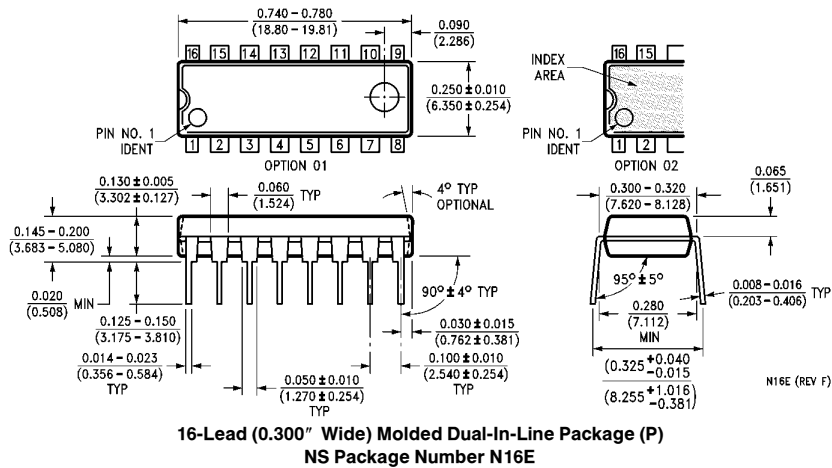
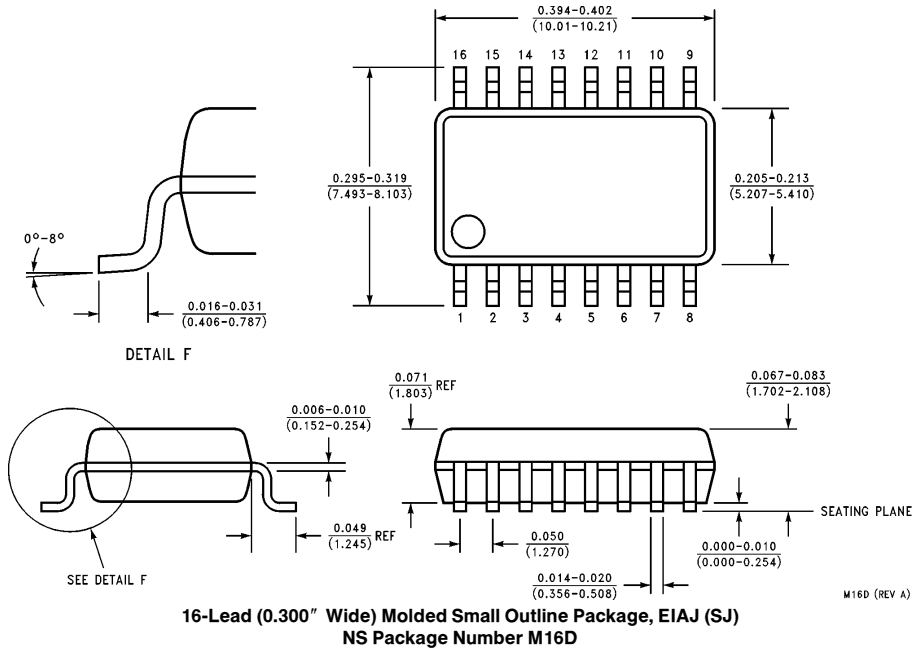
- Top View:** Shows the package footprint with dimensions:
 - Overall width: 0.785 ± 0.005 [19.94] MAX
 - Pin 1 to Pin 8 distance: 16
 - Pin 9 to Pin 8 distance: 9
 - Pin pitch: 0.220 ± 0.010 [5.59-7.87]
 - Pin diameter: $R 0.025$ [0.64]
 - Pin 8 to Pin 9 distance: $R 0.005 \pm 0.020$ TYP [0.13-0.51]
- Side View:** Shows the package height and pin dimensions:
 - Pin height: 0.037 ± 0.005 TYP [0.94 $\pm$ 0.13]
 - Pin diameter: 0.055 ± 0.005 TYP [1.40 $\pm$ 0.13]
 - Pin 1 to Pin 8 distance: 0.005 [0.13] MIN TYP
 - Pin 9 to Pin 8 distance: 0.020 ± 0.060 TYP [0.51-1.52]
 - Pin 1 to Pin 8 distance: 0.200 [5.08] MAX TYP
 - Pin 1 to Pin 8 distance: 0.125 ± 0.200 TYP [3.18-5.08]
 - Pin 1 to Pin 8 distance: 0.080 [2.03] MAX BOTH ENDS
 - Pin 1 to Pin 8 distance: 0.100 ± 0.010 TYP [2.54 $\pm$ 0.25]
 - Pin 1 to Pin 8 distance: 0.150 [3.81] MIN TYP
 - Pin 1 to Pin 8 distance: $90^\circ \pm 4^\circ$ TYP
 - Pin 1 to Pin 8 distance: 0.018 ± 0.003 TYP [0.46 $\pm$ 0.08]
- Cross-sectional View:** Shows the package profile and dimensions:
 - Overall width: 0.290 ± 0.320 [7.37-8.13]
 - Pin height: 0.180 [4.57] MAX
 - Pin diameter: 0.010 ± 0.002 TYP [0.25 $\pm$ 0.05]
 - Pin 1 to Pin 8 distance: $95^\circ \pm 5^\circ$ TYP
 - Pin 1 to Pin 8 distance: 0.310 ± 0.410 [7.87-10.41]
 - Pin 1 to Pin 8 distance: GLASS SEALANT

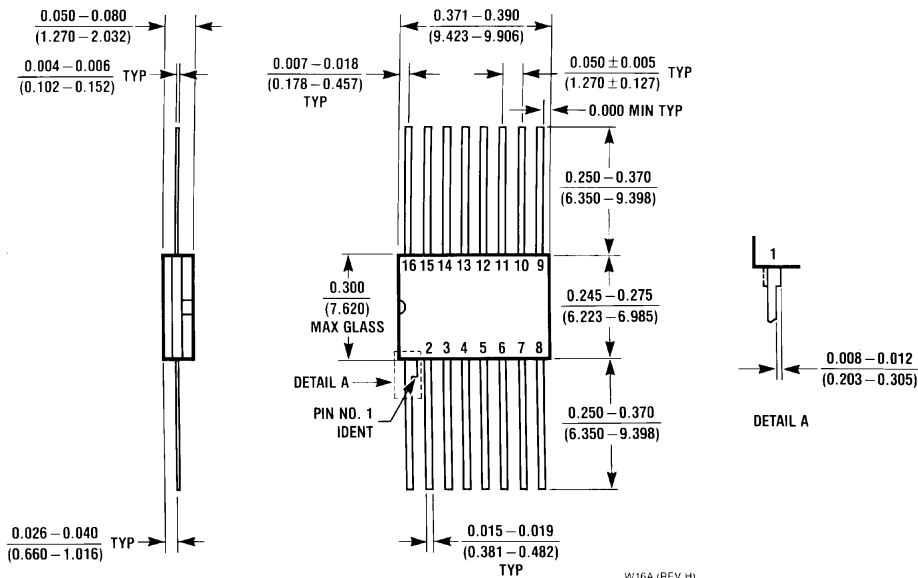
J16A (REV L)



6

Physical Dimensions inches (millimeters) (Continued)



Physical Dimensions inches (millimeters) (Continued)

16-Lead Ceramic Flatpak (F)
NS Package Number W16A

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation
 2900 Semiconductor Drive
 P.O. Box 58090
 Santa Clara, CA 95052-8090
 Tel: (408) 272-9959
 TWX: (910) 339-9240

National Semiconductor GmbH
 Livny-Gargan-Str. 10
 D-82256 Fürstenfeldbruck
 Germany
 Tel: (81-41) 35-0
 Telex: 527849
 Fax: (81-41) 35-1

National Semiconductor Japan Ltd.
 Sumitomo Chemical
 Engineering Center
 Bldg. 7F
 1-7-1, Nakase, Mihamu-Ku
 Chiba-City,
 Chiba Prefecture 261
 Tel: (043) 299-2300
 Fax: (043) 299-2500

National Semiconductor Hong Kong Ltd.
 13th Floor, Straight Block,
 Ocean Centre, 5 Canton Rd.
 Tsimshatsui, Kowloon
 Hong Kong
 Tel: (852) 2737-1600
 Fax: (852) 2736-9960

National Semicondutores Do Brasil Ltda.
 Rue Deputado Lacorda Franco
 120-3A
 Sao Paulo-SP
 Brazil 05418-000
 Tel: (55-11) 212-5066
 Telex: 391-1131931 NSBR BR
 Fax: (55-11) 212-1181

National Semiconductor (Australia) Pty. Ltd.
 Building 16
 Business Park Drive
 Monash Business Park
 Nottingham, Melbourne
 Victoria 3168 Australia
 Tel: (3) 558-9999
 Fax: (3) 558-9998

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.